# NXP BT152X-600R SCR datasheet

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Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

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## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

## 2. Features and benefits

- High blocking voltage capability
- High thermal cycling performance
- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability
- Very high current surge capability

## 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

## 4. Quick reference data

Table 1. Quie	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	600	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; t <sub>p</sub> = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	200	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_h \le 43 \text{ °C}$ ; Fig. 1; Fig. 2; Fig. 3	-	-	20	A
Static characte	eristics		 		-	-
I <sub>GT</sub>	gate trigger current	$V_D$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	3	32	mA





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#### **Pinning information** 5.

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	А <del>-Ң</del> -К
2	А	anode		G sym037
3	G	gate		
mb	n.c.	mounting base; isolated		
			TO-220F (SOT186A)	

#### **Ordering information** 6.

Table 3. Ordering i	information		
Type number	Package		
	Name	Description	Version
BT152X-600R	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A

#### **Limiting values** 7.

#### Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_h \le 43 \text{ °C}$	-	13	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_h \le 43 \text{ °C}$ ; Fig. 1; Fig. 2; Fig. 3	-	20	A
I <sub>TSM</sub>	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	200	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	220	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	200	A <sup>2</sup> s
dI <sub>T</sub> /dt	rate of rise of on-state current	$I_{T}$ = 50 A; $I_{G}$ = 0.2 A; $dI_{G}/dt$ = 0.2 A/µs	-	200	A/µs
I <sub>GM</sub>	peak gate current		-	5	Α

BT152X-600R

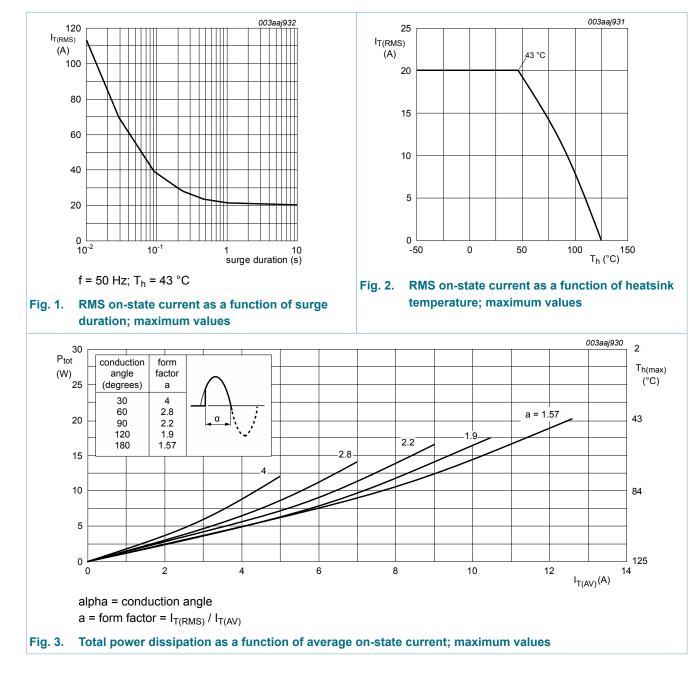
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# BT152X-600R

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Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

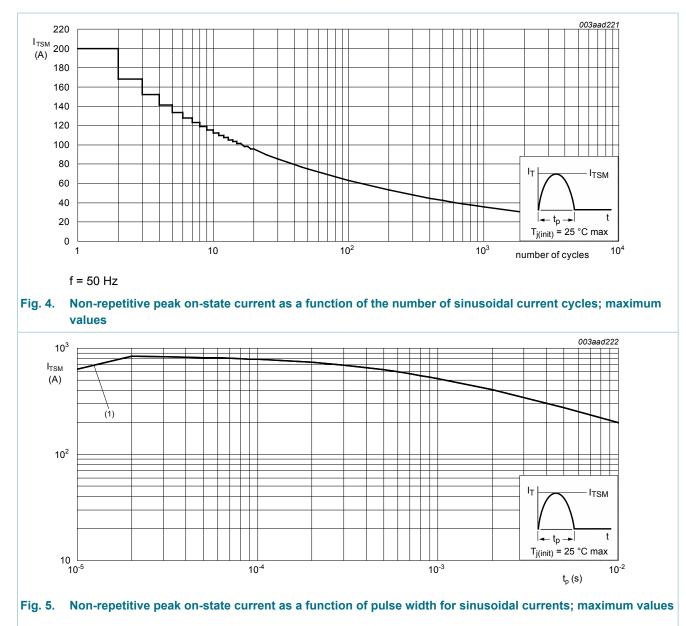


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 Product data sheet
 18 March 2014
 3 / 11

# BT152X-600R

SCR



 $t_{\rm p}~\leq~10~ms;~~(1)~dI_T/dt~limit$ 

## 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-h)</sub>	thermal resistance	with heatsink compound; Fig. 6	-	-	4	K/W
	from junction to heatsink	without heatsink compound; Fig. 6	-	-	4.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	55	-	K/W

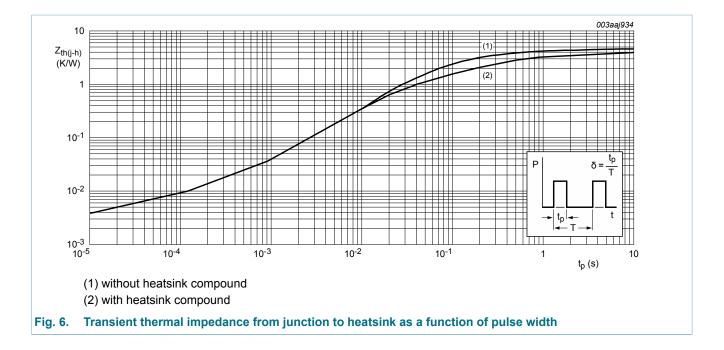
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18 March 2014

4/11

# BT152X-600R

SCR



# 9. Isolation characteristics

Table 6. Iso	olation characteristics						
Symbol	Parameter	Conditions	I	Min	Тур	Мах	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; T <sub>h</sub> = 25 °C	-	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	from anode to external heatsink; f = 1 MHz; T <sub>h</sub> = 25 °C	-	-	10	-	pF

## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	3	32	mA
۱ <sub>L</sub>	latching current	$V_D$ = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	25	80	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	15	60	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 40 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 11	-	0.6	1	V
		V <sub>D</sub> = 600 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 11	0.25	0.4	-	V

BT152X-600R

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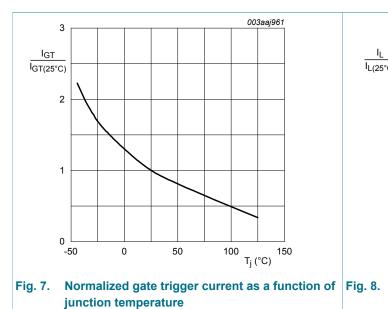
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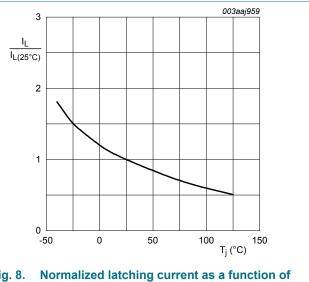
5/11

# BT152X-600R

#### SCR

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.2	1	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.2	1	mA
Dynamic char	acteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); gate open circuit; exponential waveform; Fig. 12	200	300	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 40 A; V <sub>D</sub> = 600 V; I <sub>G</sub> = 0.1 A; dI <sub>G</sub> / dt = 5 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
tq	commutated turn-off time	$\begin{split} &V_{DM} = 402 \; V; \; T_j = 125 \; ^\circ C; \; I_{TM} = 50 \; A; \\ &V_R = 25 \; V; \; (dI_T/dt)_M = 50 \; A/\mu s; \; dV_D/ \\ &dt = 30 \; V/\mu s; \; R_{GK} = 100 \; \Omega; \; (V_{DM} = 67\% \\ &of \; V_{DRM}) \end{split}$	-	70	-	μs





junction temperature

BT152X-600R

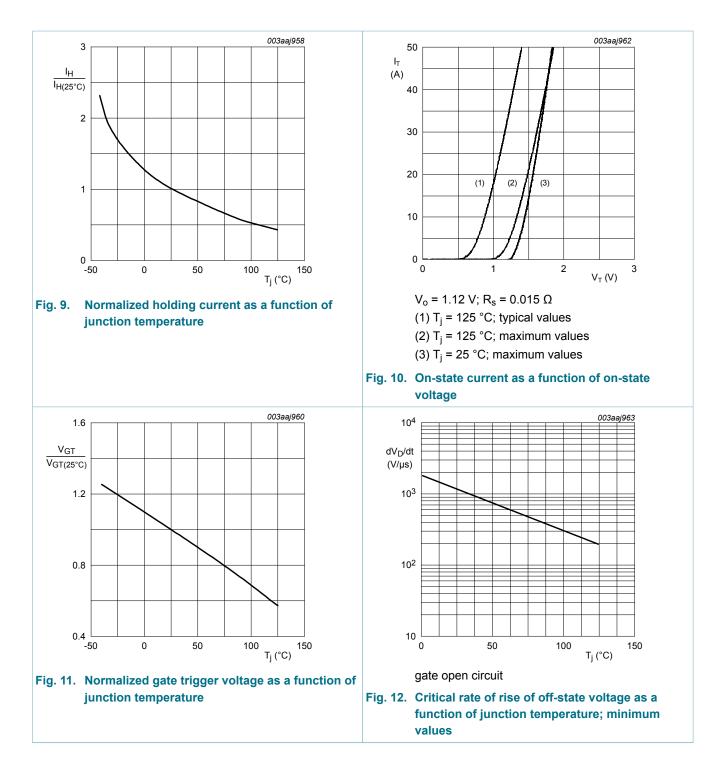
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Product data sheet

# BT152X-600R

SCR



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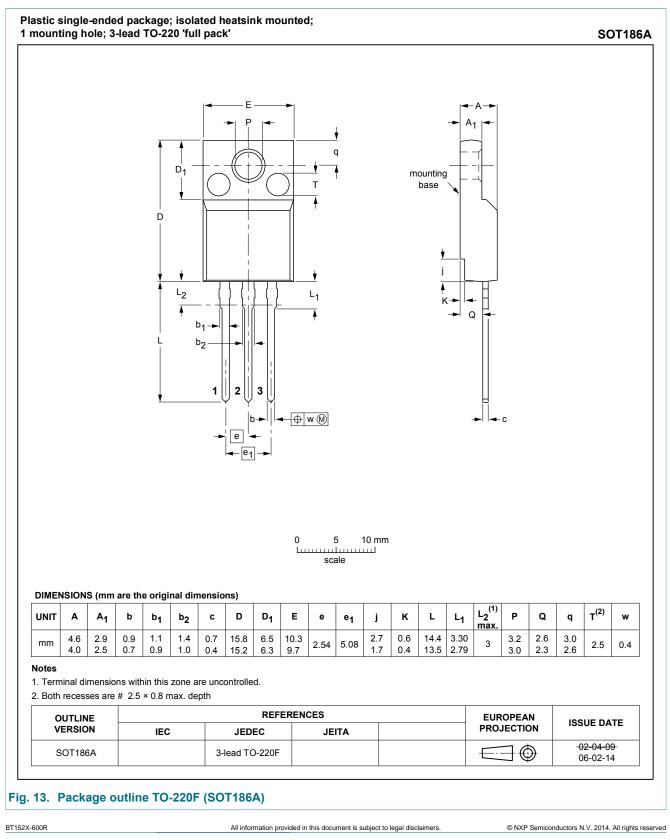
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18 March 2014

7/11

SCR

# 11. Package outline



18 March 2014

# BT152X-600R

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product data sheet

18 March 2014

9/11

SCR

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Product data sheet

18 March 2014

# **BT152X-600R**

SCR

### **13. Contents**

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Limiting values	2
8	Thermal characteristics	4
9	Isolation characteristics	5
9 10	Isolation characteristics	
•		5
10	Characteristics	5 8
10 11	Characteristics Package outline	5 8 9
10 11 12	Characteristics Package outline Legal information Data sheet status Definitions	5 8 9 9 9
<b>10</b> <b>11</b> <b>12</b> 12.1	Characteristics Package outline Legal information Data sheet status	5 8 9 9 9

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Product data sheet

18 March 2014